

Vishay Siliconix

P-Channel 2.5 V (G-S) MOSFET



Marking Code: 3B

PRODUCT SUMMARY						
V _{DS} (V)	-20					
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -4.5$ V	0.060					
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -2.7$ V	0.090					
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -2.5$ V	0.100					
Q _g typ. (nC)	6					
I _D (A) ^a	-4.7					
Configuration	Single					

FEATURES

- TrenchFET® power MOSFET
- 100 % R_g tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





	(4) S O
(3) G O —	
	(1, 2, 5, 6) D

P-Channel MOSFET

ORDERING INFORMATION	
Package	TSOP-6
Lead (Pb)-free	Si3443BDV-T1-E3
Lead (Pb)-free and halogen-free	Si3443BDV-T1-GE3

ABSOLUTE MAXIMUM RATINGS $(T_A = 28)$	5°C, unless otherwi	se noted)		
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-source voltage	V_{DS}	-20	V	
Gate-source voltage	V_{GS}	± 12	V	
Continuous drain current (T _J = 150 °C) ^a	T _A = 25 °C	- I _D	-3.6	^
	T _A = 70 °C		-2.8	
Pulsed drain current		I _{DM}	-20	Α
Continuous source current (diode conduction) ^a		I _S	-0.9	
Maximum nawar dissination 8	T _A = 25 °C	Б	1.1	10/
Maximum power dissipation ^a	T _A = 70 °C	P_{D}	0.7	W
Operating junction and storage temperature range		T _J , T _{sta}	-55 to +150	°C

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient ^a	t ≤ 5 s	R _{thJA}	50	62.5	°C/W
	Steady state		90	110	
Maximum junction-to-foot (drain)	Steady state	R _{thJF}	30	36	

Note

a. Surface mounted on FR4 board, $t \leq 5\ s$



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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static							
Gate threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	-0.6	-	-1.4	V	
Gate-body leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 12 V$	-	-	± 100	nA	
Zero gate voltage drain current	1	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	-1		
Zero gate voltage drain current	I _{DSS}	V_{DS} = -20 V, V_{GS} = 0 V, T_J = 70 °C	-	-	-5	μA	
On-state drain current ^a	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-15	-	-	Α	
		$V_{GS} = -4.5 \text{ V}, I_D = -4.7 \text{ A}$	-	0.048	0.060	Ω	
Drain-source on-state resistance a	R _{DS(on)}	$V_{GS} = -2.7 \text{ V}, I_D = -3.8 \text{ A}$	-	0.070	0.090		
		$V_{GS} = -2.5 \text{ V}, I_D = -1 \text{ A}$	-	0.080	0.100		
Forward transconductance a	9 _{fs}	$V_{DS} = -10 \text{ V}, I_{D} = -4.7 \text{ A}$	-	11	-	S	
Diode forward voltage ^a	V_{SD}	$I_S = -1.7 A$, $V_{GS} = 0 V$	-	-0.8	-1.2	V	
Dynamic ^b							
Total gate charge	Q_g		-	6	9		
Gate-source charge	Q_{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -4.7 \text{ A}$	-	1.4	-	nC	
Gate-drain charge	Q_{gd}		-	1.9	-		
Gate resistance	R_g	f = 1 MHz	5	9.5	16.2	Ω	
Turn-on delay time	t _{d(on)}		-	22	35		
Rise time	t _r	V_{DD} = - 10 V, R_L = 10 Ω	-	35	55		
Turn-off delay time	t _{d(off)}	$I_D\cong$ - 1.0 A, $V_{GEN}=$ - 4.5 V, $R_g=6~\Omega$	-	45	70	ns	
Fall time	t _f		-	25	40		
Source-drain reverse recovery time	t _{rr}	$I_F = -1.7 \text{ A}, dI/dt = 100 \text{ A/}\mu\text{s}$	-	25	50		

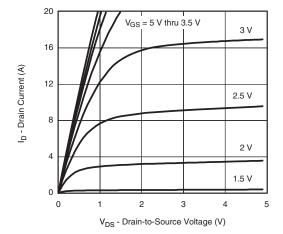
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. Guaranteed by design, not subject to production testing

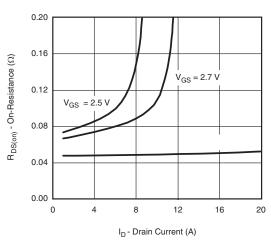
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



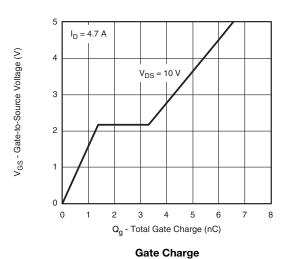
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

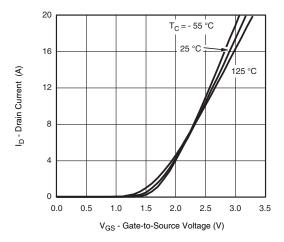


Output Characteristics

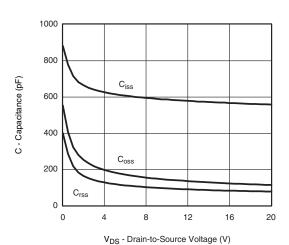


On-Resistance vs. Drain Current

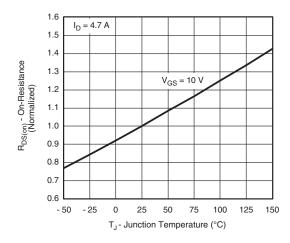




Transfer Characteristics



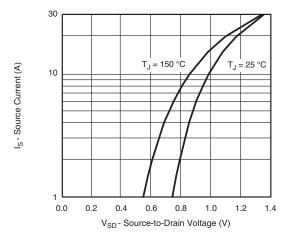
Capacitance



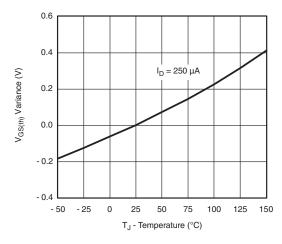
On-Resistance vs. Junction Temperature



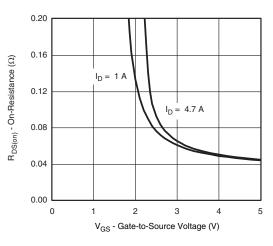
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



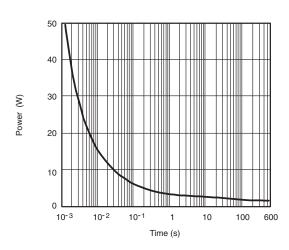
Source-Drain Diode Forward Voltage



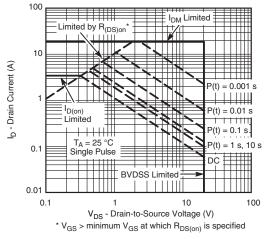
Threshold Voltage



On-Resistance vs. Gate-to-Source Voltage

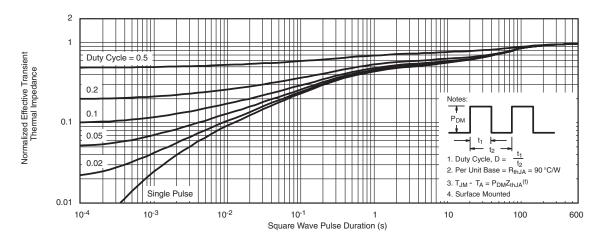


Single Pulse Power

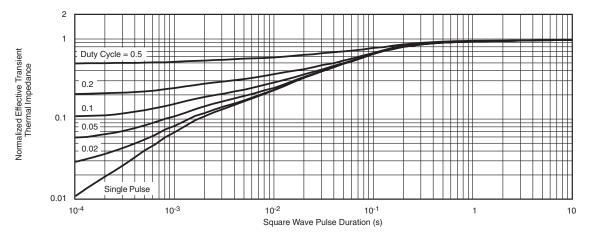




TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

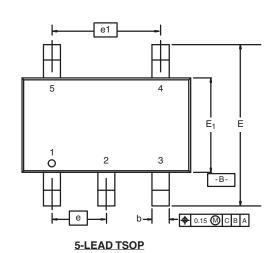
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72749.

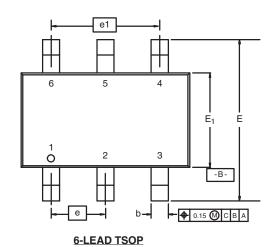


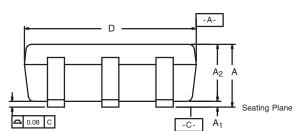


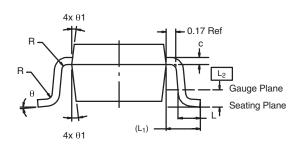
TSOP: 5/6-LEAD

JEDEC Part Number: MO-193C









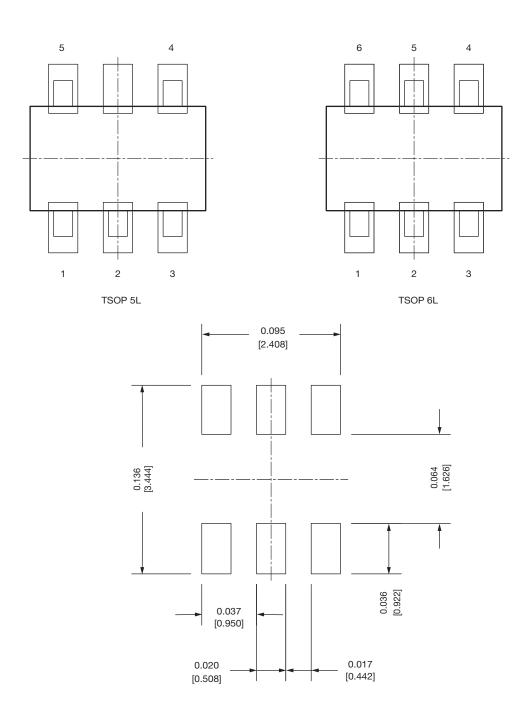
	MIL	LIMETER	RS	INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.91	-	1.10	0.036	-	0.043	
A ₁	0.01	-	0.10	0.0004	-	0.004	
A ₂	0.90	-	1.00	0.035	0.038	0.039	
b	0.30	0.32	0.45	0.012	0.013	0.018	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.95	3.05	3.10	0.116	0.120	0.122	
Е	2.70	2.85	2.98	0.106	0.112	0.117	
E ₁	1.55	1.65	1.70	0.061	0.065	0.067	
е		0.95 BSC		(0.0374 BSC	;	
e ₁	1.80	1.90	2.00	0.071	0.075	0.079	
L	0.32	-	0.50	0.012	-	0.020	
L ₁		0.60 Ref			0.024 Ref		
L ₂		0.25 BSC			0.010 BSC		
R	0.10	-	-	0.004	-	-	
θ	0°	4°	8°	0°	4°	8°	
θ_1		7° Nom 7° Nom					
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540							

Document Number: 71200 18-Dec-06

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Recommended Land Pattern For TSOP-5L / TSOP-6L



Note

• All dimensions are in inches (millimeter)

ECN: C22-0860-Rev. B, 24-Oct-2022 DWG: 3010



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